TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

## 2SA1020

# Power Amplifier Applications Power Switching Applications

- Low Collector saturation voltage:  $V_{CE}$  (sat) = -0.5 V (max) (IC = -1 A)
- High-speed switching:  $t_{stg} = 1.0 \mu s$  (typ.)
- Complementary to 2SC2655

## **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	IC	-2	Α
Collector power dissipation	PC	900	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

# 0.75MAX. 1.0MAX. 1.27 1 2 3 2.54 2.54 3. BASE Unit: mm TOSHIBA 2-5J1A

Weight: 0.36 g (typ.)

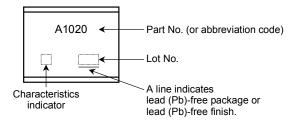
## **Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-1.0	μА
Emitter cut-off current		I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-1.0	μΑ
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-50	_	_	V
DC current gain		h <sub>FE (1)</sub>	$V_{CE} = -2 \text{ V}, I_{C} = -0.5 \text{ A}$	70	_	240	
		h <sub>FE (2)</sub>	$V_{CE} = -2 \text{ V}, I_{C} = -1.5 \text{ A}$	40	_	_	
Collector-emitter saturation voltage $V_{CE (sat)}$ $I_{C} = -1 \text{ A}, I_{B} = -0.05 \text{ A}$		$I_C = -1 \text{ A}, I_B = -0.05 \text{ A}$	_	_	-0.5	V	
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	$I_C = -1 \text{ A}, I_B = -0.05 \text{ A}$	_	_	-1.2	V
Transition frequency		f <sub>T</sub>	$V_{CE} = -2 \text{ V}, I_{C} = -0.5 \text{ A}$	_	100	_	MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	40	_	pF
Switching time	Turn-on time	t <sub>on</sub>	Output $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	_	0.1	_	
	Storage time	t <sub>stg</sub>		_	1.0	_	μS
	Fall time	t <sub>f</sub>	$-I_{B1} = I_{B2} = 0.05 \text{ A}$ DUTY CYCLE \(\leq 1\%\)	_	0.1	_	

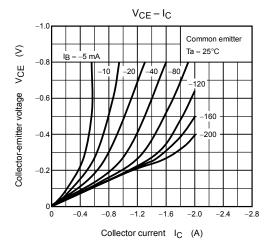
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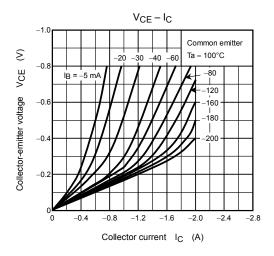
Note: hFE (1) classification O: 70 to 140, Y: 120 to 240

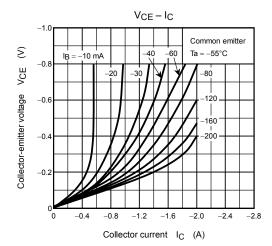
## Marking

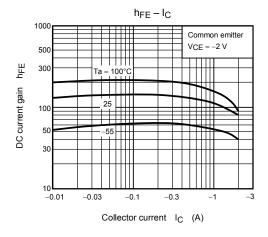


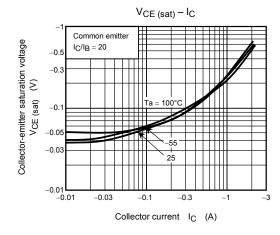
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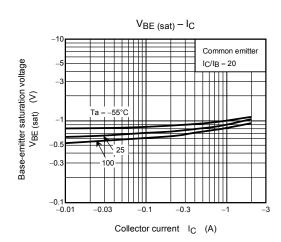


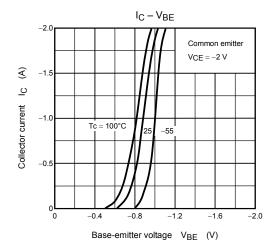


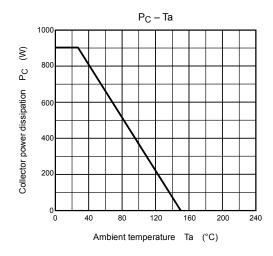


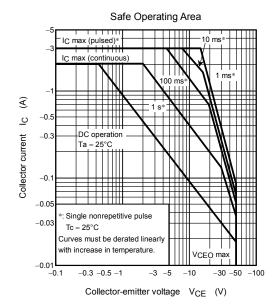












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